

**AMENDMENTS TO THE CLAIMS**

**This listing of claims will replace all prior versions and listings of claims in the application:**

**LISTING OF CLAIMS:**

1.-16. (Canceled).

17. (Currently amended): A dye-sensitized solar cell comprising a transparent electrode substrate, a working electrode having an oxide semiconductive porous film formed on the transparent electrode substrate which is made of oxide semiconductive fine particles and having a photo-sensitizing dye absorbed thereon, and a counter electrode provided opposing the working electrode, and an electrolyte layer comprising the electrolyte composition ~~according to claim 1~~ which is provided between the working electrode and the counter electrode, and wherein the electrolyte composition comprises an ionic liquid and a halogen-based redox pair, wherein the ionic liquid includes dicyanoamide anions.

18. (Original): The dye-sensitized solar cell according to claim 17 wherein the transparent electrode substrate comprises a conductive layer made of a conductive material on a transparent substrate.

19. (Original): The dye-sensitized solar cell according to claim 18 wherein the transparent substrate includes glass, a transparent plastic substrate, and a polished plate of a ceramic.

20. (Original): The dye-sensitized solar cell according to claim 18 wherein the conductive layer includes a transparent oxide semiconductor selected from the group consisting of tin-doped indium oxide (ITO), tin oxide ( $\text{SnO}_2$ ), fluorine-doped tin oxide (FTO), and mixtures thereof.

21. (Original): The dye-sensitized solar cell according to claim 18 wherein the conductive layer has a thickness of between about 0.05  $\mu\text{m}$  and 2.0  $\mu\text{m}$ .

22. (Original): The dye-sensitized solar cell according to claim 17 wherein the oxide semiconductor porous film is a porous thin layer with a thickness between about 0.5 and 50  $\mu\text{m}$  containing as a main component oxide semiconductor fine particles which include titanium oxide ( $\text{TiO}_2$ ), tin oxide ( $\text{SnO}_2$ ), tungsten oxide ( $\text{WO}_3$ ), zinc oxide ( $\text{ZnO}$ ), niobium oxide ( $\text{Nb}_2\text{O}_5$ ), and mixtures thereof, where said oxide semiconductor fine particles have an average particle diameter between 1 nm to 1000 nm.

23. (Original): The dye-sensitized solar cell according to claim 17 measuring photoelectric conversion efficiency greater than 4.5%.